

UNA0233

Transistor array to drive the small motor

Features

- Small and lightweight
- Low power consumption
- Low-voltage drive
- With 6 elements incorporated

Applications

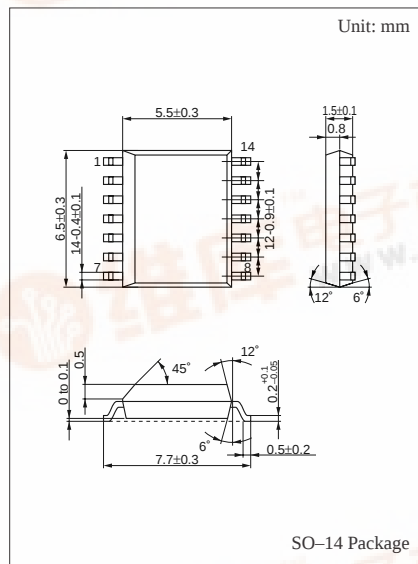
- For motor drives
- Small motor drive circuits in general

Absolute Maximum Ratings (Ta=25±3°C)

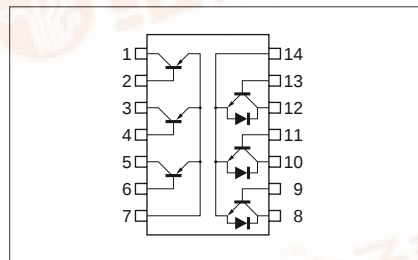
Parameter	Symbol	Ratings	Unit
Collector to base voltage	V_{CBO}	±10	V
Collector to emitter voltage	V_{CEO}	±10	V
Emitter to base voltage	V_{EBO}	±7	V
Collector current	I_C	±0.5	A
Peak collector current	I_{CP}	±1	A
Total power dissipation	P_T^*	0.5	W
Junction temperature	T_j	150	°C
Storage temperature	T_{stg}	-55 to +150	°C

Note: ± marks used above: +: NPN part, -: PNP part

* $T_C = 25^\circ\text{C}$ only when the elements are active



Internal Connection



■ Electrical Characteristics (Ta=25°C)

Parameter	Symbol	Conditions	min	typ	max	Unit
Collector to base voltage	V_{CBO}	(NPN) $I_C = 10\mu A, I_E = 0$	10			V
		(PNP) $I_C = -10\mu A, I_E = 0$	-10			
Collector to emitter voltage	V_{CEO}	(NPN) $I_C = 1mA, I_B = 0$	10			V
		(PNP) $I_C = -1mA, I_B = 0$	-10			
Emitter to base voltage	V_{EBO}	(NPN) $I_E = 10\mu A, I_C = 0$	7			V
Collector cutoff current	I_{CBO}	(NPN) $V_{CB} = 7V, I_E = 0$			1	μA
Forward current transfer ratio	h_{FE}	(NPN) $V_{CE} = 2V, I_C = 200mA^*$	200		800	
		(PNP) $V_{CE} = -2V, I_C = -100mA^*$	200		450	
Collector to emitter saturation voltage	$V_{CE(sat)}$	(NPN) $I_C = 1A, I_B = 25mA^*$			0.4	V
		(PNP) $I_C = -1A, I_B = -25mA^*$			-0.4	
Transition frequency	f_T	(NPN) $V_{CB} = 6V, I_E = -50mA, f = 200MHz$		120		MHz
		(PNP) $V_{CB} = -6V, I_E = 50mA, f = 200MHz$		190		
Collector output capacitance	C_{ob}	(NPN) $V_{CB} = 6V, I_E = 0, f = 1MHz$		25		pF
		(PNP) $V_{CB} = -10V, I_E = 0, f = 1MHz$		65		
Forward voltage	V_F	(NPN) $I_F = 0.5A$			1.3	V

*Pulse measurement